



MAINTENANCE MANUAL

(DF3166) (DF3172, IMTS)

138-174 MHz, 40 WATT POWER AMPLIFIER

19D424583G2 MOBILE "M" SERIES AND INTERMITTENT DUTY STATION

19D424583G6 MOBILE "E" SERIES 19D424786G2 CONTINUOUS DUTY STATION

19D424786G5 CONTINUOUS DUTY DUPLEX

TABLE OF CONTENTS	
DESCRIPTION	Page 1
CIRCUIT ANALYSIS	1
OUTLINE DIAGRAMS	3-4
SCHEMATIC DIAGRAM	5
PARTS LIST AND PRODUCTION CHANGES	6

DESCRIPTION

The MASTR® II modularized 40-Watt PA assembly contains a 10-watt driver module, a 40-watt PA module, power control circuitry and low pass filter. A total of three transistors, two in the 10-watt driver and one in the 40-watt PA, are used to provide rated RF output power. The output power is adjustable from 10 watts to rated output power and is held constant for normal variations in temperature and voltage.

- CAUTION -

Mobile and Station Power Amplifier Assemblies ARE NOT interchangeable due to different chassis grounding requirements.

However, the individual driver and power amplifier board may be interchanged between mobiles and stations.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298, C299 and L201 prevent RF from getting on the power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

The PA assembly is insulated from vehicle ground to permit operation in positive or negative ground vehicles.

- NOTE -

In positive ground vehicles, A - is "hot" with respect to vehicle ground. Shorting the transmitter PA printed wiring board ground pattern to the radio case may cause one of the inline fuses to blow.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8Kl2. The Test Set meters Ampl-1 drive (exciter output), power control voltage, driver and PA current.

CIRCUIT ANALYSIS

10-WATT DRIVER A201

The exciter output is coupled through an RF cable to PA input jack J201. The RF is coupled through a matching network to the base of Class C amplifier Q1. The coupling network matches the 50-ohm input to the base of Q1 and consists of A201-T1, C4, C5, and C39. R3, C3, R13 and L1 are stabilizing networks in the base circuit of Q1.

Part of the RF input is rectified by CR1 and is applied to voltage divider R1 and R2. The voltage is divided to activate the Power Control circuits and for metering the Ampl-1 drive at J205.

Collector voltage to Q1 and Q2 is controlled by the Power Control circuit, and is applied to Q1 through collector

stabilizing network L4 and R4 and collector feed network L3 and C6. The collector voltage is metered through R7 at J205-3 (Pos. C).

The output of Ql is coupled to the base of the second class C amplifier Q2 through a matching network consisting of Cl0 through Cl4 and L5 through L7. Collector voltage to Q2 is applied through collector stabilizing network L11 and R6 and collector feed network L8 and Cl5.

The output of the 10-watt driver is taken from the collector of Q2 and applied to the base of power amplifier A204-Q1 on the 40-watt PA module through an impedance matching network, two 50 ohm micro strips, W30 and a second impedance matching network.

The collector impedance matching network for A201-Q2 (L9, L10, C20 and C21) matches the output of Q2 to 50 ohm micro strip A201-W2. C22 is a DC blocking capacitor. W30 interconnects the output of the 10-watt driver to the input of the 40-watt PA module.

40-WATT PA MODULE A204

The base impedance matching network for A204-Q1 (L1-L3, C1-C4, and R1) matches the 50 ohm input impedance to the base of power amplifier A204-Q1. Collector voltage is coupled through collector stabilizing network Z1 and collector feed network L4 and C10.

Collector current for Q1 is metered across tapped manganin resistor R15 at J205-5&5. The reading is taken on the 10-volt scale with the High Sensitivity button pressed and read as 10 amperes full scale.

Following Q1 is an impedance matching network consisting of L5, L6, C7 and C9 that matches the output of Q1 to 50 ohm micro strip W2. The RF energy is then coupled through W31 and the low pass filter to the antenna.

- WARNING -

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.



The power control circuit, located on the 10-watt driver module and PA Assembly, consists of power control IC A201-U1, thermistor RT201, power adjust potentiometer A201-R8, pass transistor Q215 and the directional coupler. The power control IC senses the presence of drive power from the exciter, the heat sink temperature, power output level, reflected power, and input voltage to provide automatic power leveling across the frequency band.

When the transmitter is keyed, rectified RF from A201-CR1 is applied to pin 10 of U1, turning it on. U1 supplies a reference voltage through pin 4 to power adjust potentiometer A201-R8. The voltage appearing at the arm of R8 is applied back to pin 2 of U1. This voltage determines the base voltage of Q215. The conduction of Q215 sets the collector voltage applied to the 10-watt driver transistors A201-Q1 and Q2, thereby controlling the RF drive to the PA. The RF output power varies in direct proportion to the RF drive applied to the PA and can be adjusted from approximately 10 to 40-watts.

Once the power is set to the desired level, UI compares the setting of power adjust control R8 to the actual output power flowing through the directional coupler and adjusts the collector voltage on the 10-watt driver transistors accordingly. A204-CR1 rectifies the sensed forward power from the directional coupler and A204-R2 sets the forward power reference voltage applied to pin 1 of UI.

Reflected power is sensed by the directional coupler and rectified by A204-CR2. When the reflected power exceeds a preset level established by A204-R3, a DC voltage proportional to the reflected power is applied to pin 3 of Ul. Ul lowers the base voltage of Q215, which in turn lowers the collector voltage of A201-Q1, Q2 thereby reducing transmitter output power.

Temperature protection is provided by U1 and thermistor RT201. RT201 is mounted on the heat sink assembly. Under normal operating conditions, the temperature sensing circuit is inactive. When the heatsink temperature reaches approximately 100°C, the resistance of RT101 decreases, decreasing the base voltage of Q215. This in turn reduces the collector voltage applied to A201-Q1, Q2 reducing the transmitter output until at approximately 125°C the output power is almost zero. As the temperature of the heatsink decreases the output power increases until full power returns at approximately 100°C.



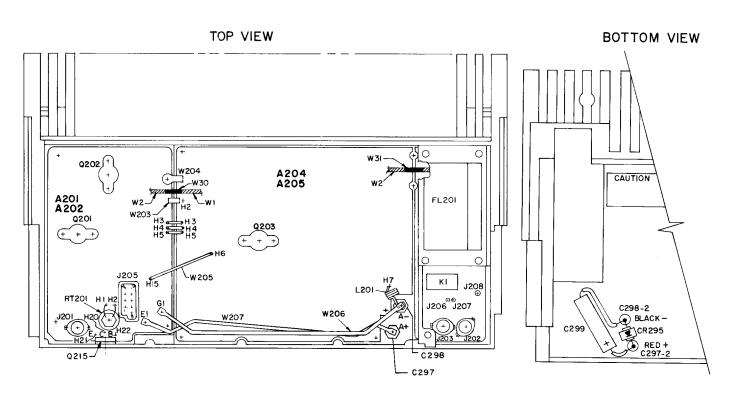
GE Mobile Communications

Overvoltage protection for the RF transistors is also provided by Ul. Should the supply voltage exceed approximately 18 volts, Ul will switch off the collector voltage to A201-Ql, Q2 turning them off and thereby removing drive to the PA. The IC will hold A201-Ql, Q2 off until the supply voltage is reduced to a safe level.

- CAUTION -

Ul may be damaged if output terminals 12 or 14 are shorted to ground. Use extreme caution when servicing the power control circuit.

MOBILE AND INTERMITTENT DUTY STATION PA



(19D429850, Rev. 1)

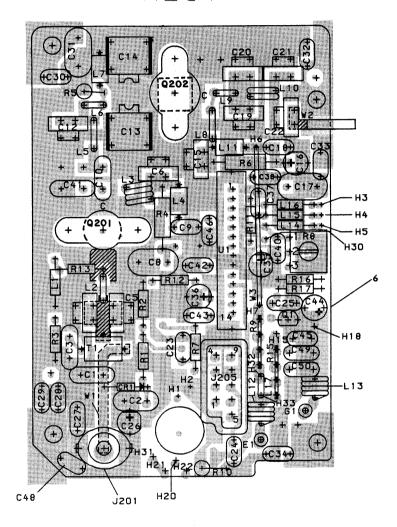
OUTLINE DIAGRAM

138-174 MHz 40 WATT POWER AMPLIFIER

LBI30751

A204

A201

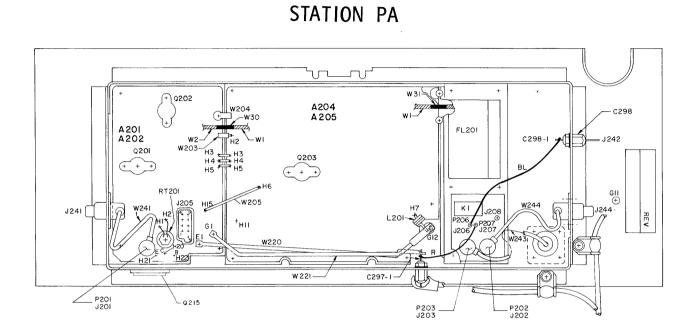


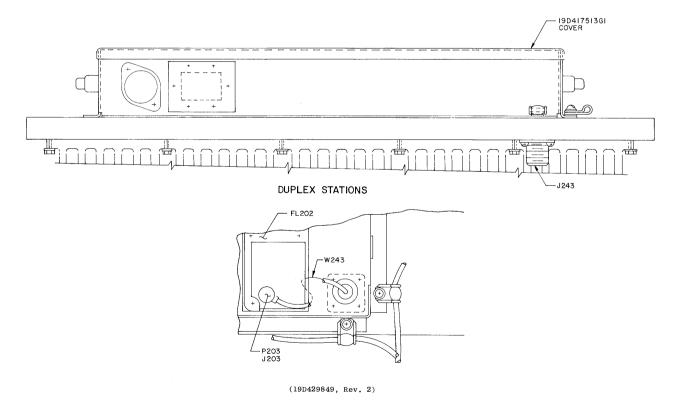
AS SHOWN OTHERWISE SAME AS PART 1.

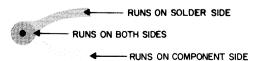
(19D424879, Rev. 14) (19B227634, Sh. 1, Rev.5) (19B227634, Sh. 2, Rev.4)

OUTLINE DIAGRAMS

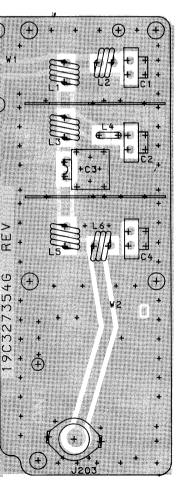
138-174 MHz, 40 WATT POWER AMPLIFIER

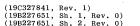


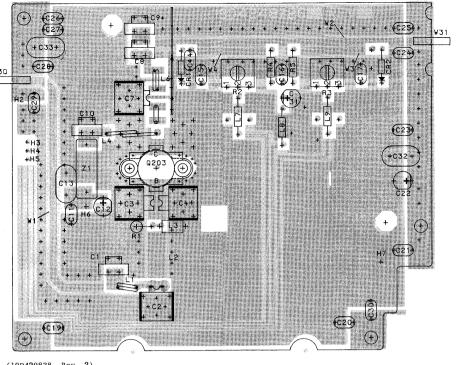




STATION FILTER

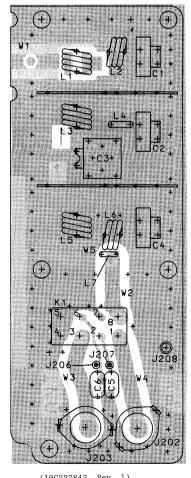




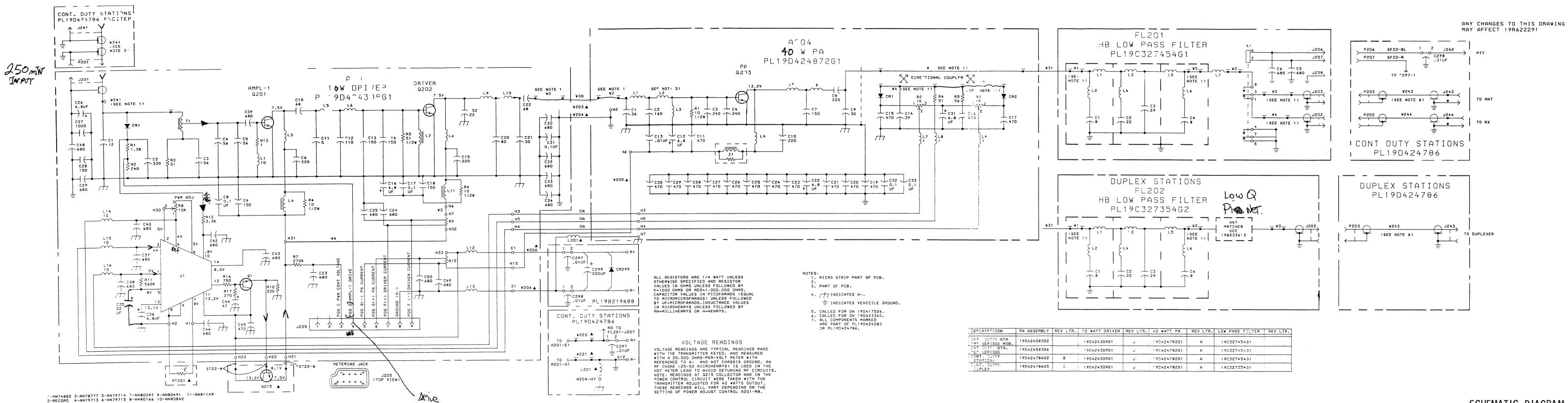


(19D429838, Rev. 2) (19B232135, Sh. 1, Rev. 1) (19B232135, Sh. 2, Rev. 1)

MOBILE & INTERMITTENT DUTY STATION FILTER



19B227654, Sh.1, Rev. 1) 19B227654, Sh.2, Rev. 1)



(19R622289, Rev. 16)

DC PROPRETIONAL

SCHEMATIC DIAGRAM

138—174 MHz, 40 WATT POWER AMPLIFIER

LBI30751

PARTS LIST 138-174 MHz POWER AMPLIFIER ASSEMBLIES 19D42458362 25 WATT "W" SERIES MARINE 19D42458363 65 WATT "M" SERIES MOBILE & INT. DUTY STATION 19D42458364 110 WATT "M" SERIES MOBILE & INT. DUTY STATION 19D42458365 25 WATT "E" SERIES MOBILE & INT. DUTY STATION 19D42458366 40 WATT "E" SERIES MARINE 19D42458367 65 WATT "E" SERIES MOBILE 19D42458367 65 WATT "E" SERIES MOBILE

SYMB0L	GE PART NO.	DESCRIPTION	Q202F
A201	19D424309G1	10 Watt Driver. (Used with 19D424583G2, G4, G6 & G8).	Q203 <i>I</i> Q203I
A202	19D424309G3	25 Watt Driver/PA. (Used with 19D424583G1, G3, G5, & G7).	Q204 and Q205
A203	19D424328G1	Coupler. (Used with 19D424583G1, G5).	Q215
A204	19D424872G1	40 Watt Power Amplifier (Used with 19D424583G2, G6).	RT20
A205	19D424872G2	65 Watt Power Amplifier. (Used with 19D424583G3, G7).	
A206	19D424266G1	110 Watt Power Amplifier. (Used with 19D424583G4, G8).	W203 W204
FL201			W205 W206
		19C327454G1	W207 W208
C1	19A116679P8D	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.	W209
C1 C2	19A700015P12	Teflon/Mica: 22 pF ±5%, 250 VDCW.	W210
C2 C3	19A116795P29J	Teflon: 29 pF ±5%, 250 VDCW.	W211
C4	19A116679P8D	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.	
C5 and C6	19A116655P18	Ceramic disc: 680 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
J202 and J203	19A700049P2	JACKS AND RECEPTACLES Connector, receptacle: 500 VDCW maximum; sim to NTTF-1058.	C297 and C298
J206 and J207	19A134263P2	Contact, electrical: sim to Selectro 229-1071.	C299
J208	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	CR29
		RELAYS	
К1	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CPClare HFW-1201558, or Potter-Brumfield HCM6160.	
		INDUCTORS	
L1	19A129569P1	Coil.	
L2	19A701418P1	Coil.	
L3	19A129569P1	Coil.	
L4	19A701420P5	Coil.	1
L5	19A129569P1	Coil.	
L6	19A701418P1	Coil.	1
L7	19A136907P1	Coil.	
W1 thru W5			
		1	

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
L201	19A129562P1	INDUCTORS		N80P13006C6	Machine screw, phillips head: No. 6-32 x 3/ (Secures A201-A206 boards).
and L202				N80P9006C6	Machine screw: No. 4-40 x 3/8. (Used with mounting).
				N402P5C6	Flatwasher, steel: No. 4. (Used with Q215 mounting).
 Q201	19A134340P1	Silicon, NPN: VHF Amplifier, 4 watts, 12.5 v.			· ·
Q202A	19A134340P3	Silicon, NPN: VHF Amplifier, 12 watts.		7141225P2	Hex nut: No. 4-40. (Used with Q215 mounting

GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	INDUCTORS		N80P13006C6	Machine screw, phillips head: No. 6-32 x 3/8.
19A129562P1	Coil.		N80P9006C6	(Secures A201-A206 boards). Machine screw: No. 4-40 x 3/8. (Used with Q215
				mounting).
19A134340P1	Silicon, NPN: VHF Amplifier, 4 watts, 12.5 v.		N402P5C6	Flatwasher, steel: No. 4. (Used with Q215 mounting).
19A134340P3	Silicon, NPN: VHF Amplifier, 12 watts.		7141225P2	Hex nut: No. 4-40. (Used with Q215 mounting).
19A134340P2	Silicon, NPN: NHF Amplifier, 25 watts, 12.5 v.		19A129434P1	Washer, fiber. (Used with C297 & C298).
19A134340P4	Silicon, NPN, VHF Amplifier: 45 w.		19B219929P1	Support, heat sink.
19A134387P1	Silicon, NPN.		19B209209P306	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8. (Secures support to heat sink - Quantity 3).
19A134387P1	Silicon, NPN.		19A129639P1	Cover, heat sink.
	a.v. www		19B201074P305	Tap screw, Phillips POZIDRIV®: No. 6-32 x 5/16. (Secures heat sink cover).
19A116742P1	Silicon, NPN.		19D416275P2	Filter casting. (FL201).
				·
19A129379G1	Thermistor: 40K ohms $\pm 20\%$, color code white; sim to Carborundum Type M0806J-5.			
10419004001				
19A136942P1 7878455P1	Strap. Lug terminal; sim to GE89473.			
198227912P1	Jumper.			
19B227931G3	Jumper.			
19B227931G1	Jumper.			
19B227074G1	Jumper. 6 inches long.			
19B226725G1	Jumper. 5-3/4 inches long.			
19B227934G1	Cable: approx 13 inches long.			
19A137006P2	Jumper.			
	HEAT SINK ASSEMBLY 19B219688G7 "M" SERIES 19B219688G19 "E" SERIES			
19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20 amps; sim to Erie 327050X5W0103P.			
19A115680P10	Electrolytic: 200 uF +150-10%, 18 VDCW; sim to Mallory Type TTX.			
	DIODES AND RECTIFIERS			
19A116783P1	Rectifier, silicon: 100 VDC blocking, 6 amp; sim to MR751.			
	MISCELLANEOUS			
19D416732G7	Heat sink. ("M" SERIES).			
19D417105G7	Heat sink. ("E" SERIES).			
19A700068P1	Insulator, bushing. (Used with Q215).			
19A700115P3 19C321982P1	Insulator, plate. (Used with Q215). Insulator. (Located under A201, A202).			
19C321442P1	Insulator. (Located under A203-A206).			
NP280427	Nameplate. (25, 40, 65 Watt - Located on FL201).			
NP280428	Nameplate. (110 Watt - Located on FL201).			
19B201074P306	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8. (Located between FL201 cover and A203-A206 - Quantity 2).			
N404P13C6	Lockwasher, internal tooth: No. 6. (Located between FL201 cover and A203-A206).			
19B201074P312	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/4. (Secures FL201 cover).			
N44P9010C6	Machine screw: No. 4-40 x 5/8. (Secures Q1 & Q2 on A201, A202; Q1 on A204, A2095, Q1-Q3 on A206).			

PARTS LIST

138-174 MHz POWER AMPLIFIER ASSEMBLIES 19D424786G2-G9 ISSUE 9

•	GE PART NO.	DESCRIPTION
		19D424786G2 40 WATT CONTINUOUS DUTY STATION 19D424786G3 65 WATT CONTINUOUS DUTY STATION 19D424786G4 110 WATT CONTINUOUS DUTY STATION 19D424786G5 40 WATT CONTINUOUS DUTY DUPLEX STA. 19D424786G6 65 WATT CONTINUOUS DUTY DUPLEX STA. 19D424786G7 110 WATT CONTINUOUS DUTY DUPLEX STA. 19D424786G8 130 WATT CONTINUOUS DUTY DUPLEX STA. 19D424786G9 130 WATT CONTINUOUS DUTY COMBINING ANTENNA TUNER
A201	19D424309G1	10 Watt Driver. (Used with 19D424786G2, G4, G5, G7).
A202	19D424309G3	25 Watt Driver. (Used with 19D424786G3, G6).
A204	19D424872G1	40 Watt Power Amplifier. (Used with 19D424786G2, G5).
A205	19D424872G2	65 Watt Power Amplifier. (Used with 19D424786G3, G6).
A206	19D424266G1	110 Watt Power Amplifier. (Used with 19D424786G4, G7).
A207	19D424266G2	130 Watt Power Amplifier. (Used with 19042478668, G9).
2297 and	19A116708P1	
2298		
L201		COMPONENT BOARD 19C327454G1
C1	19A116679P8D	
C2	19A700015P12	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW. Teflon/Mica: 22 pF ±5%, 250 VDCW.
C3	19A116795P29J	Teflon: 29 pF ±5%, 250 VDCW.
C4	19A116679P8D	Metallized teflon: 8 pF +0.5 pF, 250 VDCW.
C5 and C6	19A116655P18	Ceramic disc: 680 pF ±10%, 1000 VDCW; sim to RMC Type JF Discap.
J202 and J203	19A700049P2	Connector, receptacle: 500 VDCW maximum; sim to NTTF-1058.
J206 and J207	19A134263P2	Contact, electrical: sim to Selectro 229-1071.
J208	4033513P4	Contact, electrical: sim to Bead Chain L93-3.
К1	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CPClare HFW-1201558, or Potter-Brumfield HCM6160.
L1	19A129569P1	
L2	19A129569P1 19A701418P1	Coil.
L3	19A129569P1	Coil.
L3	19A701420P5	Coil.
L4 L5	19A129569P1	Coil.

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	L6	19A701418P1	Coil.	FL203		COMPONENT BOARD 19C327354G1					19A701863P13	Cable clip. (Located near J243 - Quantity 2).
	L7	19A136907P1	Coil.				P206	4036634P1	Contact, electrical; sim to AMP 42428-2.	1	19B209268P113	Terminal, solderless: sim to AMP 2-34835-4. (Solders to C297-2).
				C1	104116670D0D						7491823P13	Terminal, solderless. (Used on power ground wire
	W1 thru		(Part of printed board 19D424357P1).	C2	19A116679P8D 19A700015P12	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW. Teflon/Mica: 22 pF ±5%, 250 VDCW.	Q201	19A134340P1	Silicon, NPN: VHF Amplifier, 4 watts, 12.5 v.		7139898P3	at PA). Nut, hex, brass: No. 1/4-28. (Secures C297 &
	₩5			C3	19A116795P29J	Teflon: 29 pF ±5%, 250 VDCW.	Q202A	19A134340P3	Silicon, NPN: VHF Amplifier, 12 watts.		710000000	C298).
ļ	FL202*		COMPONENT BOARD 19C327354G1	C4	19A116679P8D	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.	Q202B	19A13434CP2	Silicon, NPN: NHF Amplifier, 25 watts, 12.5 v.		N80P13016C6	Machine screw, phillips head: No. 6-32 x 1. (Secures FL201 casting - Quantity 5).
		İ	(Deleted by REV. B)			TACKS AND DESCRIPTIONS	Q203A	19A134340P4	Silicon, NPN, VHF Amplifier: 45 w.		19B201074P308	Tap screw, Phillips POZIDRIV®: No. 6-32 x 1/2.
on .				J203	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to	Q203B	19A134387P1	Silicon, NPN.			(Located between FL201 casting and A204-A206 - Grounds FL201 shield).
N STA.	C1	19A116679P8D	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.			NTTF-1058.	Q204 and	19A134387P1	Silicon, NPN.		N44P9010B6	Machine screw: No. 4-40 x 5/8. (Secures Q1, Q2 on A201 & A202, Q1-Q3 on A204-A2060.
STA.	C2	19A700015P12	Teflon/Mica: 22 pF ±5%, 250 VDCW.				Q205				19B201074P320	Tap screw, Phillips POZIDRIV®: No. 6-32 x 1-1/4.
ING	C3 C4	19A116795P29J 19A116679P8D	Teflon: 29 pF ±5%, 250 VDCW.	L1	19A129569P1	Coil.	Q215	19A116753P1	Silicon, NPN; sim to Type 2N5302.			(Secures L201 & W221 at spacer).
	C.*	194110079765	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.	L2	19A701418P1	Coil.		10411674001	Earlier than REV A:		19B201074P204	Tap screw, phillips POZIDRIV®: No. 4-40 x 1/4. (Secures J243 & J244).
G5,			JACKS AND RECEPTACLES	L3	19A129569P1	Coil.		19A116742P1	Silicon, NPN.		19B209103P410	Tap screw, hex head: No. 8-32 x 5/8. (Secures heat sinks).
	J203	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058.	L4	19A701420P5	Coil.			THERMISTORS		19B201074P306	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8.
.				L5	19A129569P1	Coil.	RT201	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborundum Type M0806J-5.			(Secures cable clip loops and power ground terminal).
86G2,	L1	19A129569P1		L6	19A701418P1	Coil.					19A134260P1	Insulator cover. (Used with Q215).
	L2	19A729369P1 19A701418P1	Coil.				WOOD	10110001011			4029974P1	Insulator, plate: aluminum. (Used with Q215).
86G3,	L3	19A129569P1	Coil.	W1 and		(Part of printed board 19D424362P1).	W203 W204	19A136942P1 7878455P1	Strap.		19A115222P3	Washer, shield. (Used with Q215).
	L4	19A701420P5	Coil.	W2			W205	19B227912P1	Lug terminal; sim to GE89473. Jumper.		4036994P1	Terminal, solderless. (Used with Q215).
1	L5	19A129569P1	Coil.			ANTENNA MATCHER	W210	19822793461	Cable: approx 13 inches long.			,
1	L6	19A701418P1	Coil.			19C330778G1	W211	19A137006P2	Jumper.	ļ		
							W214	19A129312614	Antenna Cable.			
	W1		(Part of printed board 19D424362P1).	C1A	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 Special.	W220	19B227931G2	Jumper.			
İ	and W2			C2	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson	W221	19B22793164	Jumper.			
	FL202*		ANTENNA FILTER W MATCHER			187-0109-005.	W243		CABLE ASSEMBLY			
			19C327354G2 (Added by REV. B)	C3A	19A116656P15J0	Ceramic disc: 15 pF ±5%, 500 VDCW, temp coef 0 PPM.			19A129312G6			
			ANTENNA FILTER	C4A	19A700008P2	Variable: 2.28 to 14.13 pF; sim to EF Johnson 187-0109-005.			JACKS AND RECEPTACLES		-	
			19D432248G1	C5A	19A116656P10J0	Ceramic disc: 10 pF ±0.5 pF, 500 VDCW, temp coef	J203		Connector. Includes:			
						О РРМ.		19A700067F1 4029082P2	Receptacle, coaxial: sim toAmphenol 83-798.			
	C1	19A116679P8D	Metallized teflon: 8 pF ±0.5 pF, 250 VDCW.			DIODES AND RECTIFIERS		4023002F2	Cover.			
	C2	19A700015P12	Teflon/Mica: 22 pF ±5%, 250 VDCW.	CR1	19A700047P3	Silicon: 100 mW; sim to 1N6263.						
	C3	19A116795P29J	Teflon: 29 pF <u>+</u> 5%, 250 VDCW. Metallized teflon: 8 pF <u>+</u> 0.5 pF, 250 VDCW.			INDUCTORS	P203	5491689P108	Plug. (Includes 10 inches of RF cable).			
o RMC		19A116679P8D	metallized tellon. 8 pr +0.5 pr, 250 vbcm.	L1A	19A143343P1	Coil.	₩244	5491689P104	Cable, RF: approx 4 inches long. (Includes J244).			
			JACKS AND RECEPTACLES						MISCELLANEOUS			
	J1 thru	19A116364P2	Contact, electrical; sim to AMP 86182-7.	R1	19A700106P31	Composition: 47 ohms ±5%, 1/4 w.		19A134016P1	Insulator, bushing. (Used with Q215). (Not			
m to	J4 J203	19A700049P2	Connector, receptacle: 500 VDCW maximum; sim to						Used).	ļ		
	3203	194700049P2	NTTF-1058.	J213		JACKS AND RECEPTACLES		19A116023P3	Insulator, plate. (Used with Q215). (Not Used).			
71.				0210	19A701869P1	Consists of: Housing.		19C321982P1 19C321442P1	Insulator. (Located under A201 & A202). Insulator. (Located under A204-A206).			
3.	L1	19A129569P1	Coil.		19A701869P2	Contact, electrical.		19B219404G1	Shield electrical. (Located under FL201			
	L2	19A701418P1	Coil.	J214		Part of W214.			casting).			
	L3	19A129569P1	Coil.	J242		Part of C298.		19D416275P2	Casting. (FL201).			
	L4	19A701420P5	Coil.	J243		Part of W243.		19D417513G1 19B226212G1	PA Cover.			
	L5	19A129569P1	Coil.	J244		Part of W244.		19822621261	Heat sink. (The 3 center heat sinks on 75, 100, 110 WATT & the only 2 heat sinks on the 40, 65 WATT power amplifiers).			
	L6	19A701418P1	Coil.					19B226212G2	Heat sink. (Located on J243 end of the 75, 100,			
1				L201	19A129562P4	Coil.			110 WATT Power amplifiers - Quantity 1).			
	W1 thru		(Part of printed circuit board 19D432086P1).	L202	19A129562P3	Coil.		19B226212G3	Heat sink. (Located on W241 end of the 75, 100, 110 WATT Power amplifiers - Quantity 1).			
	W3							7150186P127	Spacer. (Termination for L201 & W221).			
							1	N529P18C6	Plug button. (Used when C298 is not used - Duplex).			
					*		1					
			[

PARTS LIST

A201 138-174 MHz, 10 WATT DRIVER 19D424309G1 ISSUE 9

C10A			
C1A 19A700105P8 Mica: 12 pF + or -5%, 500 VDCW. 7489162P39 Silver mica: 330 pF + or -5%, 500 VDCW; sim to Sprague Type 118. C3 19A700105P28 Mica: 56 pF + or -5%, 500 VDCW. C4A 19A70015P23 Teflon/Mica: 56 pF + or -5%, 250 VDCW. C6 19A70015P37 Teflon/Mica: 22 pF + or -5%, 250 VDCW. C7 19A116080P107 Polyoster: 0.1 uF + or -10%, 50 VDCW. C8 19A106080P107 Polyoster: 0.1 uF + or -10%, 50 VDCW. C9 19A16655P8 Ceramic disc: 150 pF + or -10%, 1000 VDCW; sim. to SMC Type JF Discap. C10A 19A70015P30 Mica: 68 pF + or -5%, 500 VDCW. C11A 7489162P101 Silver mica: 5 pF + or -10%, 500 VDCW; sim. to Sprague Type 118. C12 19A700015P30 Silver mica: 110 pF + or -5%, 250 VDCW. C13A 19A700014P33 Metalized teflon: 150 pF + or -5%, 250 VDCW. C14A 19A700015P37 Teflon/Mica: 220 pF + or -5%, 250 VDCW. C15 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C16 19A134202P15 Tantalum: 6.8 uF + or -10%, 500 VDCW; sim. to SWC Type JF Discap. C20A 19A700015P27 Teflon/Mica: 30 pF + or -5%, 250 VDCW. C21A 19A700015P27 Silver mica: 68 pF + or -5%, 250 VDCW. C22B 19A136655P18 Ceramic disc: 150 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C26 19A134202P15 Tantalum: 6.8 uF + or -5%, 250 VDCW. C27 19A116655P18 Ceramic disc: 1600 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C28 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C29 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C30 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C31 19A116655P18 Tantalum: 22 uF + or -20%, 35 VDCW. C22 19A134202P15 Tantalum: 22 uF + or -20%, 35 VDCW. C32 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C33 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C40 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C29 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RNC Type JF Discap. C40 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; s	MBOL GE	PART NO.	DESCRIPTION
C2			
Sprague Type 118.	ClA 19	A700105P8	Mica: 12 pF + or -5%, 500 VDCW.
C4A and C5A an	C2 74	89162P39	
C6A C6 19A700015P37 C6 19A10605P37 C7 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A116655P8 C8 19A11665SP8 C8 19A10015P30 C11A C11A C12 19A700015P30 C13A C13A C13A C14A C15 C19 C19 C19 C19 C19 C19 C19 C19 C19 C19	C3 19	A700105P28	Mica: 56 pF + or -5%, 500 VDCW.
C6 19A700015P37 C8 19A116080P107 C9 19A116055P8 C0 19A116055P8 C10A 19A700105P30 C11A 7489162P101 C11A 7489162P101 C12 19A700015P30 C13A 19A700015P30 C14A 19A700015P30 C15 19A700015P30 C16 19A700015P30 C17 19A11605SP8 C18 19A700015P30 C18 19A700015P30 C19A 19A700015P30 C19A 19A700015P30 C19A 19A700015P30 C19A 19A700015P37 C19A 19A700015P37 C19A 19A700015P37 C19A 19A116080P107 C19A 19A116080P107 C19A 19A11605SP8 C19A 19A700015P37 C19A 19A11605SP8 C19A 19A700015P37 C20A 19A700015P37 C21A 19A700015P37 C22B 19A1065SP8 C22B 19A100015P25 C22B 19A100015P25 C22B 19A100015P25 C22B 19A1065SP18 C22B 19A11665SP18 C22B 19A11665SP18 C22B 19A134202P15 C27 C28 19A134202P15 C29 C29 19A134202P15 C29 19A134202P15 C29 19A134202P15 C29 19A11665SP18 C20A 19A116	and	A700015P23	Teflon/Mica: 56 pF + or -5%, 250 VDCW.
C10A 19A700105930 Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap. C11A 7489162P101 Silver mica: 5 pF + or - 10%, 500 VDCW; sim. to Sprague Type 118. C12 19A700015P30 Silver mica: 5 pF + or - 10%, 500 VDCW; sim. to Sprague Type 118. C13 19A700014P33 Metallized teflon: 150 pF + or - 5%, 250 VDCW. C15 19A700015P37 Teflon/Mica: 220 pF + or - 5%, 250 VDCW. C16 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C17 19A116080P107 Polyester: 0.1 uF + or -10%, 50 VDCW. C18 19A100015P27 Silver mica: 82 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap. C20A 19A700015P26 Teflon/Mica: 30 pF + or -5%, 250 VDCW. C21A 19A700015P27 Silver mica: 82 pF + or -5%, 250 VDCW. C22B 19A700015P25 Silver mica: 68 pF + or -5%, 250 VDCW. C22B 19A700015P25 Silver mica: 68 pF + or -5%, 250 VDCW. C22B 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C27 19A116655P18 Ceramic disc: 600 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C28 19A116655P18 Ceramic disc: 150 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C29 and 19A116655P18 Ceramic disc: 600 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C31 19A116080P107 Polyester: 0.1 uF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C32 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C33 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C34 19A134202P6 Tantalum: 22 uF + or -20%, 15 VDCW. C37 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C40 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C41 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C42 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C43 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol., 16 VDCW; sim. to RMC Type JF Discap. C	C6 19	A700015P37	Teflon/Mica: 220 pF + or -5%, 250 VDCW.
to RMC Type JF Discap. Mica: 68 pF + or -5%, 500 VDCW. Silver mica: 5 pF + or -10%, 500 VDCW; sim. to Sprague Type 118. 19A700015P30 Silver mica: 110 pF + or -5%, 250 VDCW. 19A700015P37 Metallized teflon: 150 pF + or -5%, 250 VDCW. 19A700015P37 Teflon/Mica: 220 pF + or -5%, 250 VDCW. 19A16080P107 Polyester: 0.1 uF + or -20%, 35 VDCW. 19A116655P8 Ceramic disc: 150 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 22B 19A700015P27 Silver mica: 82 pF + or -5%, 250 VDCW. 22B 19A700015P25 Silver mica: 68 pF + or -5%, 250 VDCW. 22B 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 22C 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. 22B 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 22C 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. 22T 19A116655P18 Ceramic disc: 1000 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 22B 19A116655P18 Ceramic disc: 150 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 22C 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. 22C 19A134202P15 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 231 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 232 19A134202P15 Tantalum: 22 uF + or -20%, 15 VDCW. 233 19A134202P15 Tantalum: 22 uF + or -20%, 15 VDCW. 234 19A134202P15 Tantalum: 6.8 uF + or -20%, 15 VDCW. 235 19A134202P15 Tantalum: 22 uF + or -20%, 15 VDCW. 246 19A134202P15 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 247 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 248 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 249 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 240 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim. to RMC Type JF Discap. 241 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim. to RMC Type JF Discap. 242 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VD	C8 19	All6080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.
T489162P101 Silver mica: 5 pF + or - 10%, 500 VDCW; sim. to Sprague Type 118.	C9 19	A116655P8	Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap.
Sprague Type 118.	C10A 19	A700105P30	Mica: 68 pF + or -5%, 500 VDCW.
19A700014F33	C11A 74	89162P101	Silver mica: 5 pF + or - 10%, 500 VDCW; sim. to Sprague Type 118.
C14A C15	C12 19	A700015P30	Silver mica: 110 pF + or -5%, 250 VDCW.
C16	and	A700014P33	Metallized teflon: 150 pF + or - 5%, 250 VDCW.
C17		A700015P37	Teflon/Mica: 220 pF + or -5%, 250 VDCW.
C18	C16 19	A134202P15	Tantalum: 6.8 uF + or -20%, 35 VDCW.
19A700015P27 Silver mica: 82 pF + or -5%, 250 VDCW.	C17 19	All6080Pl07	Polyester: 0.1 uF + or -10%, 50 VDCW.
Teflon/Mica: 30 pF + or -5%, 250 VDCW.	C18 19	Al16655P8	
C228	C20A 19	A700015P27	Silver mica: 82 pF + or -5%, 250 VDCW.
C23 thru C25 C26 19A134202P15 Tantalum: 6.8 uF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C27 19A116655P19 C28 19A116655P18 C29 19A116655P8 C29 19A116655P18 C20 19A116655P18 C29 19A116655P18 C20 19A116655P18 C20 19A116655P18 C20 19A116655P18 C20 19A116655P18 C21 19A116655P18 C22 19A11665P18 C23 19A11665P18 C24 19A11665P18 C25 19A134202P6 C26 19A134202P6 C37 19A134202P6 C38 19A134202P6 C39 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C30 19A134202P6 C31 19A116655P18 C32 19A134202P6 C33 19A134202P6 C34 19A134202P1 C54 19A116655P18 C55 19A134202P1 C55 19A134202P1 C56 19A134202P1 C67 19A116655P18 C68 19F + or -20%, 15 VDCW. C64 19A116655P18 C68 19F + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C68 19A703314P4 C69 19A703314P4 C69 19A703314P4 C60 19A70304P4 C70 19A70304P4 C70 19A70304P4 C70 19A70304P4 C70 19A70304P4 C70 19A70304P4	C21A 19	A700015P16	Teflon/Mica: 30 pF + or -5%, 250 VDCW.
thru C25 19Al34202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C27 19Al16655P19 Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C28 19Al16655P8 Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim to RMC Type JF Discap. C29 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C31 19Al16080P107 Polyester: 0.1 uF + or -10%, 50 VDCW. C32 thru C34 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C35 19Al34202P6 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C36 19Al34202P15 Tantalum: 22 uF + or -20%, 15 VDCW. C37 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C40 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C41 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C42 19A10602P13 Ceramic disc: 680 pF + or -20%, 1000 VDCW; sim to Type JF Discap. C43 19A116655P18 Ceramic disc: 680 pF + or -20%, 1000 VDCW; sim to Panasonic LS Series. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Type JF Discap. C45 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C46 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 thru C50	С22В 19	A700015P25	Silver mica: 68 pF + or -5%, 250 VDCW.
C27 19Al16655P19 Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. C28 19Al16655P8 Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim to RMC Type JF Discap. C29 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C30 C31 19Al16080P107 Polyester: 0.1 uF + or -10%, 50 VDCW. C32 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C35 19Al34202P6 Tantalum: 22 uF + or -20%, 15 VDCW. C36 19Al34202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C37 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C40 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic disc: 680 pF + or -20%, 1000 VDCW; sim to Type JF Discap. C46 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to Type JF Discap. C47 C48 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 C48 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	thru	Al16655P18	
Sim to RMC Type JF Discap.	C26 19	A134202P15	Tantalum: 6.8 uF + or -20%, 35 VDCW.
C29 and C30 C31 19Al16655P18 C22 and C32 19Al16655P18 C32 thru C34 C35 19Al34202P6 C36 C37 19Al16655P18 C37 C38 19Al16655P18 C39 C39 C30 C30 C31 19Al1665SP18 C30 C31 C31 C32 C33 C34 C35 C35 C36 C37 C36 C37 C37 C40 C40 C40 C41 C42 C42 C43 C43 C44 C44 C45 C46 C47 C48 C48 C48 C48 C48 C48 C48	C27 19	Al16655P19	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
and to RMC Type JF Discap. C31 19Al16080P107 Polyester: 0.1 uF + or -10%, 50 VDCW. C32 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C34 19Al34202P6 Tantalum: 22 uF + or -20%, 15 VDCW. C35 19Al34202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C37 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C40 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic: 470 pF + or - 20%, 1000 VDCW; sim to Type JF Discap. C46 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	C28 19	Al16655P8	Ceramic disc: 150 pF + or - 10%, 1000 VDCW; sim. to RMC Type JF Discap.
C32 thru C34 C35 19A134202P6 Tantalum: 22 uF + or -20%, 15 VDCW. C36 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. C37 thru C40 C42 19A116655P18 C44 19A703314P4 C15 C44 19A703314P4 C25 C45 C46 19A116655P18 C67 C67 C68 C68 C68 C69 C79 C79 C79 C79 C79 C79 C79	and	Al16655P18	
to RMC Type JF Discap. 19A134202P6 Tantalum: 22 uF + or -20%, 15 VDCW. 19A134202P15 Tantalum: 6.8 uF + or -20%, 35 VDCW. 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C42 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic disc: 470 pF + or - 20%, 1000 VDCW; sim to Type JF Discap. C46 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 thru C50 C68 C68 C68 C68 C68 C68 C68 C68 C68 C6	C31 19	A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.
C35 19A134202P6 Tantalum: 22 uf + or -20%, 15 VDCW. C36 19A134202P15 Tantalum: 6.8 uf + or -20%, 35 VDCW. C37 thru C40 C42 19A116655P18 Ceramic disc: 680 pf + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uf -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic 470 pf + or -20%, 1000 VDCW; sim to Type JF Discap. C46 19A116655P18 Ceramic 470 pf + or -20%, 1000 VDCW; sim to Type JF Discap. C47 Ceramic disc: 680 pf + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 19A116655P18 Ceramic disc: 680 pf + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	thru	A116655P18	
C36	i	A134202P6	Tantalum: 22 uF + or -20%. 15 VDCW.
C37 thru C40 C42 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C42 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic disc: 680 pF + or -20%, 1000 VDCW; sim to Type JF Discap. C46 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 thru C50 C48 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	į į		
C42 and C43	C37 19		Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim
C44 19A703314P4 Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series. C45 19A701602P13 Ceramic: 470 pF + or - 20%, 1000 VDCW; sim to Type JF Discap. C46 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 thru C50 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	C42 19	Al16655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.
C45 19A701602P13 Ceramic: 470 pF + or - 20%, 1000 VDCW; sim to Type JF Discap. C46 19A116655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 thru C50 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.		A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim
C46 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap. C48 19Al16655P18 Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim to RMC Type JF Discap.	C45 19	A701602P13	Ceramic: 470 pF + or - 20%, 1000 VDCW; sim to
C48	C46 19	Al16655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim
C50		Al16655P18	Ceramic disc: 680 pF + or -10%, 1000 VDCW; sim
C52 19A700006P17 Mica: 22 pF + or -5%, 250 VDCW; sim to	C50	A700006P17	Mica: 22 pF + or -5%, 250 VDCW; sim to

	SYMBOL	GE PART NO.	DESCRIPTION	S
			RECTIPIERS	
	CR1	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	
	El	19A134263P1	Contact, electrical: sim to Selectro 229-1082-00-0-590.	
	G1	19A134263P1	Contact, electrical: sim to Selectro 229-1082-00-0-590.	
			·	
	J201	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to	
	J205	19B219374G1	Connector: 9 contacts.	
	Ll	19A700024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res	
	L3A	19A136530P1	Coil.	
	L4	19A701091G1	Coil.	
	L5A	19A136532P2	Coil.	
	L6	19A701420P5	Coil.	
,	L7	19A701091G1	Coil.	
	L8A	19A129561P1	Coil.	
	L9A	19A701420P3	Coil.	
	L10A	19A129561P1	Coil.	
	L11	19A701091G1	Coil.	
	L12	19A129569P1	Coil.	
	L13	19A701419P3	Coil.	
	L14 thru L16	19A700024P25	Coil, RF: 10.0 uH + or - 10%, 3.70 ohms DC res max.	
	Q1	19A700023P1	Silicon, NPN; sim to Type 2N3904.	
		·	RESISTORS	
	R1	19A700106P67	Composition: 1.5K ohms + or - 5%, 1/4 w.	.
	R2	3R152P241J	Composition: 240 ohms + or -5%, 1/4 w.	
	R3	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.	
	R4	19A700113P15	Composition: 10 ohms + or - 5%, 1/2 w.	
	R5A	19A700113P32	Composition: 51 ohms + or - 5%, 1/2 w.	
	R6	19A700113P15	Composition: 10 ohms + or - 5%, 1/2 w.	
	R7	3R152P274J	Composition: 270K ohms + or -5%, 1/4 w.	
	R8A	19A116559P106	Variable cermet: 10K ohms + or - 20%, 1/2 w; sim to CTS Series 360.	
	R9	19C850605P2	Shunt resistor.	
	R10	19A700113P51	Composition: 330 ohms + or - 5%, 1/2 w.	
	R11 R12	3R152P564J 19A700106P75	Composition: 560K ohms + or -5%, 1/4 w. Composition: 3.3K ohms + or - 5%, 1/4 w.	
	R13	H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.	
l	R15	19C850605P2	Shunt resistor.	
	R16	19A700106P61	Composition: 820 ohms + or - 5%, 1/4 w.	
	R17	19A700106P49	Composition: 270 ohms + or -5%, 1/4 w.	
	T1	19A129564G1	Transformer.	
	-			-
	_			
	U1	19D429709G3	IC, Power Control.	
ľ				
		1		
ı i	I	ı		

	SYMBOL	GE PART NO.	DESCRIPTION
	wl and w2 w3 w4	19B227912P1 19B227912P2 19A701093P2	
-			
_		,	
_			

LBI30751

PARTS LIST

SYMBOL	GE PART NO.	DESCRIPTION
C1A	19A700015P18	Metallized teflon: 36 pF ±5%, 250 VDCW.
C2A	19A116795P160J	Silver mica: 160 pF ±5%, 250 VDCW.
C3A and C4A	19A700014P38	Metallized teflon: 240 pF ±5%, 250 VDCW.
C7A	19A700014P33	Metallized teflon: 150 pF ±5%, 250 VDCW.
C8	19A700015P37	Teflon/Mica: 220 pF ±5%, 250 VDCW.
C9A	19A700015P16	Teflon/Mica: 30 pF ±5%, 250 VDCW.
C10A	19A700015P37	Teflon/Mica: 220 pF ±5%, 250 VDCW.
C11	19A116655P13	Ceramic disc: 470 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C12	19A134202P15	Tantalum: 6.8 uF ±20%, 35 VDCW.
C13	19A116080P107	Polyester: 0.1 uF ±10%, 50 VDCW.
C14A	19A700105P23	Mica: 39 pF ±5%, 500 VDCW.
C15 thru C17	19A116655P13	Ceramic disc: 470 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C19 thru C21	19A116655P13	Ceramic disc: 470 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C22	19A134202P15	Tantalum: 6.8 uF ±20%, 35 VDCW.
C23 thru C30	19A116655P13	Ceramic disc: 470 pF ±20%, 1000 VDCW; sim to RM(
C31	19A134202P15	Tantalum: 6.8 uF ±20%, 35 VDCW.
C32 and C33	19A116080P107	Polyester: 0.1 uP ±10%, 50 VDCW.
000		DIODES AND RECTIFIERS
CR1 and CR2	19A116052P2	Silicon, fast recovery; sim to Hewlett Packard 5082-2811.
L1A	19A136533P1	Coil.
L2		(Part of printed board 19D424845P1).
L3	19A701091G1	Coil.
L4A	19A701848P1	Coíi.
L5A	19A137271P1	Coil.
L6A	19A129561P1	Coil.
L7 thru L9	19A700024P13	Coil, RF: 1.0 uH ±10%.
		RESISTORS
R1A	7147161P17	Composition: 1.5 ohms ±5%, 1/2 w.
R2 and R3	19A700109P1	Variable, cermet: 1K ohms ±20%, 1/4 w.
R4	19A700106P32	Composition: 51 ohms ±5%, 1/4 w.
R5A	19A700106P33	Composition: 56 ohms ±5%, 1/4 w.
W1 thru W4		(Port of printed board 19D424845P1).
W30 and W31	19A701093P2	Strap.

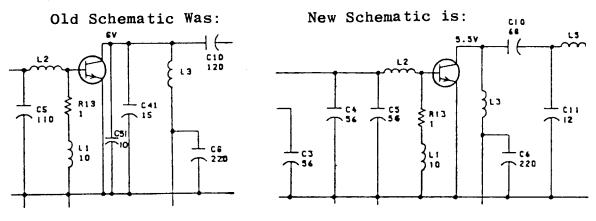
19B219649G1 Filter. Includes: L1 19A129346G2 Coil. R1 3R78P100K Resistor, composition: 10 ohms ±10%, 1 w.	SYMBOL	GE PART NO.	DESCRIPTION
L1 19A129346G2 Coil. Resistor, composition: 10 ohms ±10%, 1 w			
R1 3R7SP100K Resistor, composition: 10 ohms ±10%, 1 w	Z 1	19B219649G1	Filter. Includes:
19A139361P2 Shield.	L1	19A129346G2	Coil.
19A139361F2 Shield.	R1	3R78P100K	Resistor, composition: 10 ohms ±10%, 1 w.
		19A139361P2	MISCELLANEOUS
. 1			

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circiuts are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all pervious revisions. Refer to the Parts List for the descriptions of parts affected by these revisions.

- REV. A 10 WATT DRIVER 19D424309G1
 To improve operation when Solid State Scientific, Inc. (SSS) transistors are used for Q201. Delete C39. Change C11 and
- REV. B To improve operation when Communication Transistor Corp. (CTC) transistors are used for Q201. Delete C39, add L2. Changed C11 and added C51.
- REV. C To improve operation when TRW transistors are used for Q201. Deleted C51 and L2. Added C39 and changed C11.



- REV. D To improve performance. Changed R5.
- REV. E To improve operation of power control circuit. Added C51.
- REV. F To delete components not required with improved Power Control IC. Deleted C51.
- REV. A 40 WATT POWER AMPLIFIER 19D424872 To improve operation. Changed R1.
- REV. B PA ASSEMBLY 19D424786G5
 To incorporate new antenna matching unit FL202.
 FL202 was: 19C327354G1.
- REV. H 10 WATT DRIVER 19D424309G1
 To reduce transmitter spurs. Added C52.
- REV. J 10 WATT POWER AMPLIFIER 19D424309G1
 To improve operation of power amplifier by modifying power control circuit to eliminate overshoot at key-on. Added Q1, C44, C45, R16, and R17.